

SLG7RN45323

GreenPAK ™

DVK-RA6-powersupervision

General Description

Renesas SLG7RN45323 is a low power and small form device. The SoC is housed in a 1.6mm x 1.6mm STQFN package which is optimal for using with small devices.

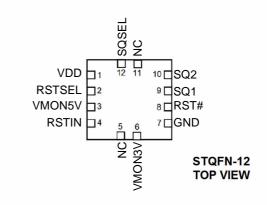
Features

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 12 Package

Output Summary

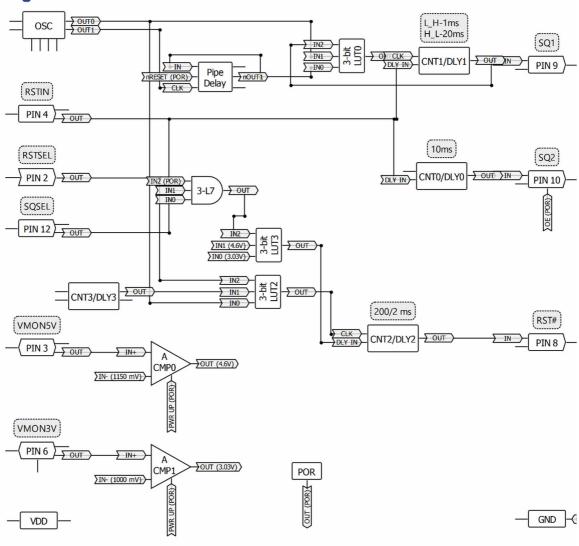
1 Output - Open Drain NMOS 1X 2 Outputs - Push Pull 1X

Pin Configuration





Block Diagram





Pin Configuration

Pin#	Pin Name	Type Pin Description		Internal Resistor
1	VDD	PWR	Supply Voltage	
2	RSTSEL	Digital Input	Digital Input Digital Input without Schmitt trigger	
3	VMON5V	Analog Input/Output	Analog Input/Output	floating
4	RSTIN	Digital Input	Digital Input with Schmitt trigger	10kΩ pullup
5	NC	Keep Floating or Connect to GND		
6	VMON3V	Analog Input/Output	Analog Input/Output	floating
7	GND	GND	Ground	
8	RST#	Digital Output	Open Drain NMOS 1X	floating
9	SQ1	Digital Output	Push Pull 1X	floating
10	SQ2	Digital Output Push Pull 1X		floating
11	NC	Keep Floating or Connect to GND		
12	SQSEL	Digital Input without Schmitt		1MΩ pulldown

Ordering Information

Part Number	Package Type
SLG7RN45323V	STQFN-12 – Tape and Reel (3k units)





Absolute Maximum Conditions

Parameter	Min.	Max.	Unit	
Supply Voltage on VDD relative	to GND	-0.5	7	V
DC Input Voltage		GND - 0.5V	VDD + 0.5V	V
Maximum Average or DC Current	Push-Pull 1x		12	mA
(Through pin)				
Current at Input Pin	-1.0	1.0	mΑ	
Input leakage (Absolute Val	ue)		1000	nA
Storage Temperature Rang	je	-65	150	°C
Junction Temperature		150	°C	
ESD Protection (Human Body N	2000		V	
ESD Protection (Charged Device	1000		V	
Moisture Sensitivity Level	,	1		

Electrical Characteristics

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
V_{DD}	Supply Voltage		1.71	5	5.5	V
T _A	Operating Temperature		-40	25	85	°C
C_{VDD}	Capacitor Value at VDD			0.1		μF
Cin	Input Capacitance			4		pF
ΙQ	Quiescent Current	Static inputs and floating outputs		76		μA
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD	V
Ivdd	Maximum Average or DC Current Through VDD Pin (Per chip side, see Note 2)	T _J = 85°C			73	mA
Ivdd	Maximum Average or DC Current Through VDD Pin (Per chip side, see Note 2)	T _J = 110°C			35	mA
Ignd	Maximum Average or DC Current Through GND Pin (Per chip side, see Note 2)	T _J = 85°C			92	mA
I _{GND}	Maximum Average or DC Current Through GND Pin (Per chip side, see Note 2)	T _J = 110°C			44	mA
		Logic Input at VDD=1.8V	1.100		VDD	V
		Logic Input at VDD=3.3V	1.780		VDD	V
		Logic Input at VDD=5.0V	2.640		VDD	V
VıH	HIGH-Level Input Voltage	Logic Input with Schmitt Trigger at VDD=1.8V	1.270		VDD	V
		Logic Input with Schmitt Trigger at VDD=3.3V	2.130		VDD	V
		Logic Input with Schmitt Trigger at VDD=5.0V	3.160		VDD	V
		Logic Input at VDD=1.8V	0		0.690	V
VIL	LOW-Level Input Voltage	Logic Input at VDD=3.3V	0		1.210	V
		Logic Input at VDD=5.0V	0		1.840	V



		Logic Input with Schmitt Trigger at VDD=1.8V	0		0.440	V
		Logic Input with Schmitt Trigger at VDD=3.3V	0		0.950	V
		Logic Input with Schmitt Trigger at VDD=5.0V	0		1.510	V
		Push-Pull 1X, Open Drain PMOS 1X, I _{OH} =100µA, at VDD=1.8V	1.680	1.790		V
V _{ОН}	HIGH-Level Output Voltage	Push-Pull 1X, Open Drain PMOS 1X, I _{OH} =3mA, at VDD=3.3V	2.720	3.090		V
		Push-Pull 1X, Open Drain PMOS 1X, I _{OH} =5mA, at VDD=5.0V	4.170	4.740		٧
		Push-Pull 1X, I _{OL} =100µA, at VDD=1.8V		0.020	0.030	V
		Push-Pull 1X, I _{OL} =3mA, at VDD=3.3V		0.180	0.280	V
Vol	LOW-Level Output Voltage	Push-Pull 1X, I _{OL} =5mA, at VDD=5.0V		0.230	0.330	V
VOL	LOVV-Level Output Voltage	Open Drain NMOS 1X, I _{OL} =100µA, at VDD=1.8V		0.010	0.020	V
		Open Drain NMOS 1X, IoL=3mA, at VDD=3.3V		0.090	0.130	V
		Open Drain NMOS 1X, IoL=5mA, at VDD=5.0V		0.120	0.160	V
		Push-Pull 1X, Open Drain PMOS 1X, V _{OH} =VDD-0.2V, at VDD=1.8V	1.000	1.390		mA
Іон	HIGH-Level Output Current (Note 1)	Push-Pull 1X, Open Drain PMOS 1X, V _{OH} =2.4V, at VDD=3.3V	6.010	10.150		mA
		Push-Pull 1X, Open Drain PMOS 1X, V _{OH} =2.4V, at VDD=5.0V	21.980	29.001		mA
		Push-Pull 1X, VoL=0.15V, at VDD=1.8V	0.760	1.340		mA
		Push-Pull 1X, V _{OL} =0.4V, at VDD=3.3V	4.060	6.440		mA
loL	LOW-Level Output Current	Push-Pull 1X, V _{OL} =0.4V, at VDD=5.0V	6.010	9.730		mA
	(Note 1)	Open Drain NMOS 1X, V _{OL} =0.15V, at VDD=1.8V	1.530	2.670		mA
		Open Drain NMOS 1X, V _{OL} =0.4V, at VDD=3.3V	8.130	12.410		mA
		Open Drain NMOS 1X, V _{OL} =0.4V, at VDD=5.0V	11.760	19.460		mA
R _{PULL_UP}	Internal Pull Up Resistance	Pull up on PIN 4		10		kΩ
R _{PULL_DOWN}	Internal Pull Down Resistance	Pull down on PINs 2, 12		1		ΜΩ
T _{DLY0}	Delay0 Time	At temperature 25°C	9.22	10	10.69	ms



		At temperature -40 +85°C (Note 3)	8.62	10	12.65	ms
		At temperature 25°C	7.26	7.84	8.35	ms
T _{CNT3}	Counter3 Period	At temperature -40 +85°C (Note 3)	6.78	7.84	9.88	ms
		Low to High transition, at temperature 25°C	4400		4793	mV
Vious	Analog Comparator0	Low to High transition, at temperature -40 +85°C (Note 3)	4250		4859	mV
V ACMP0	V _{ACMP0} Threshold Voltage	High to Low transition, at temperature 25°C	4399		4792	mV
		High to Low transition, at temperature -40 +85°C (Note 3)	4248		4857	mV
		Low to High transition, at temperature 25°C	2855		3130	mV
Vacmp1	Analog Comparator1	Low to High transition, at temperature -40 +85°C (Note 3)	2763		3175	mV
V ACMP1	Threshold Voltage	High to Low transition, at temperature 25°C	2854		3129	mV
		High to Low transition, at temperature -40 +85°C (Note 3)	2760		3174	mV
Tsu	Startup Time	From VDD rising past 1.35 V		0.31		ms
PONTHR	Power On Threshold	V _{DD} Level Required to Start Up the Chip	1.180	1.353	1.516	V
POFF _{THR}	Power Off Threshold	V _{DD} Level Required to Switch Off the Chip	0.730	0.914	1.103	V

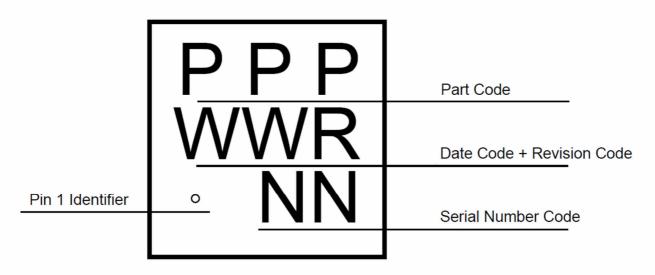
Note:

- 1. DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.
- 2. The GreenPAK's power rails are divided in two sides. Pins 2, 3, 4, 5 and 6 are connected to one side, pins 8, 9, 10, 11 and 12 to another.
- 3. Guaranteed by Design.





Package Top Marking



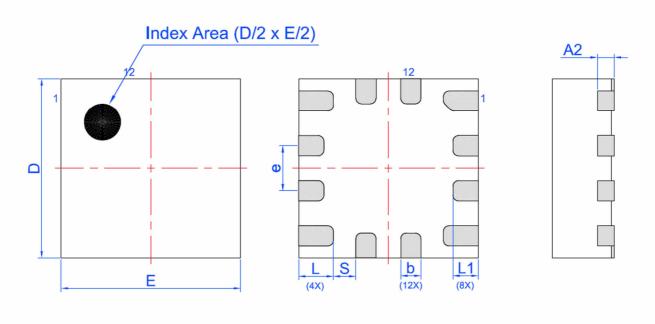
Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Revision	Date
0.11	001	U	0x85F199C6			07/11/2023

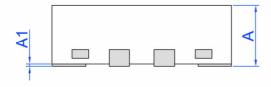
The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.



Package Drawing and Dimensions

12 Lead STQFN FCA Package 1.6 x 1.6 mm





Unit: mm

Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
Α	0.50	0.55	0.60	D	1.55	1.60	1.65
A1	0.005	•	0.060	E	1.55	1.60	1.65
A2	0.10	0.15	0.20	L	0.26	0.31	0.36
b	0.13	0.18	0.23	L1	0.175	0.225	0.275
е	0.40 BSC			S		0.2 REF	

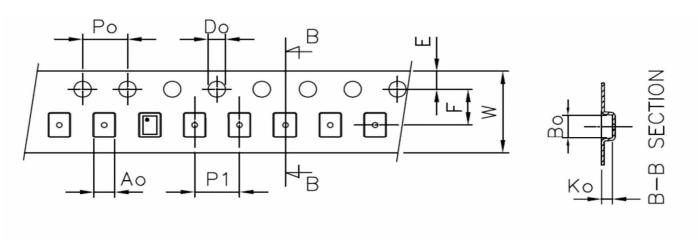


Tape and Reel Specification

		Nominal	Max Units Leader (min)		r (min)	Trailer (min)		Таре	Part		
Package Type	# of Pins	Package Size [mm]	per Reel	per Box	Reel & Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 12L FCA 0.4P Green	12	1.6x1.6x0.55	3000	3000	178/60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	Α0	В0	K0	P0	P1	D0	E	F	W
STQFN 12L FCA 0.4P Green	1.80±0.05	1.80±0.05	±0.7	4	4	1.5	1.75	3.5	8



Recommended Reflow Soldering Profile

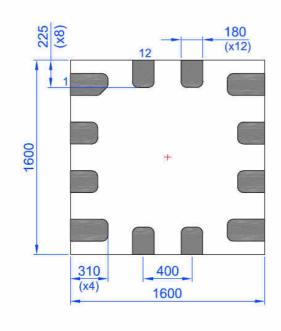
Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 1.408 mm³ (nominal). More information can be found at www.jedec.org.

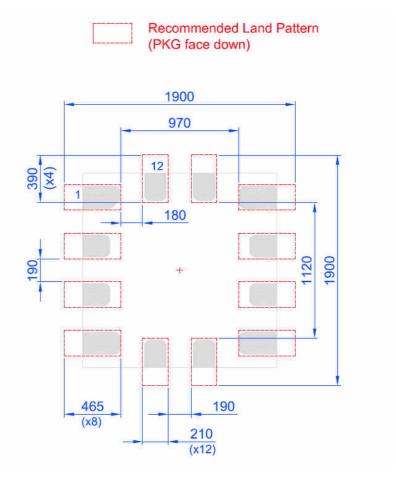


Recommended Land Pattern



Units: µm







Datasheet Revision History

Date	Version	Change
10/21/2021	0.10	New design
07/11/2023	0.11	Moved to Renesas template

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